

# Crystal Imperfections

# Perfect Crystals - Natural

Diamonds



~ 3.6x3.2x1.3 cm

Sapphire



~5x3x2 cm

Ruby



~ 2x2x1 cm

Emerald



30x 10x 10 cm

What is the common attribute between them ?

# Man made perfect crystals

Lab grown diamonds



Si ingot



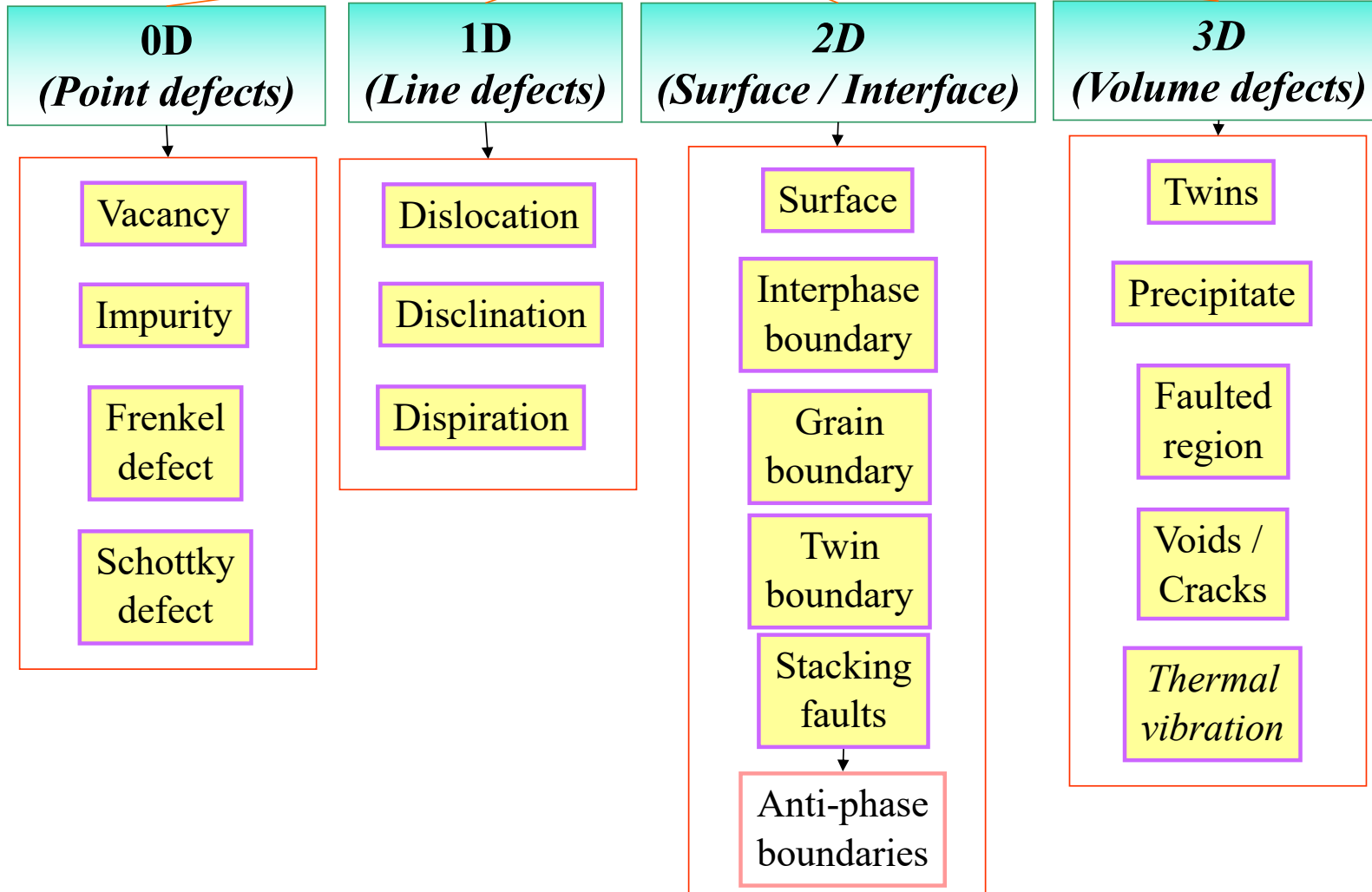
Single crystal quartz

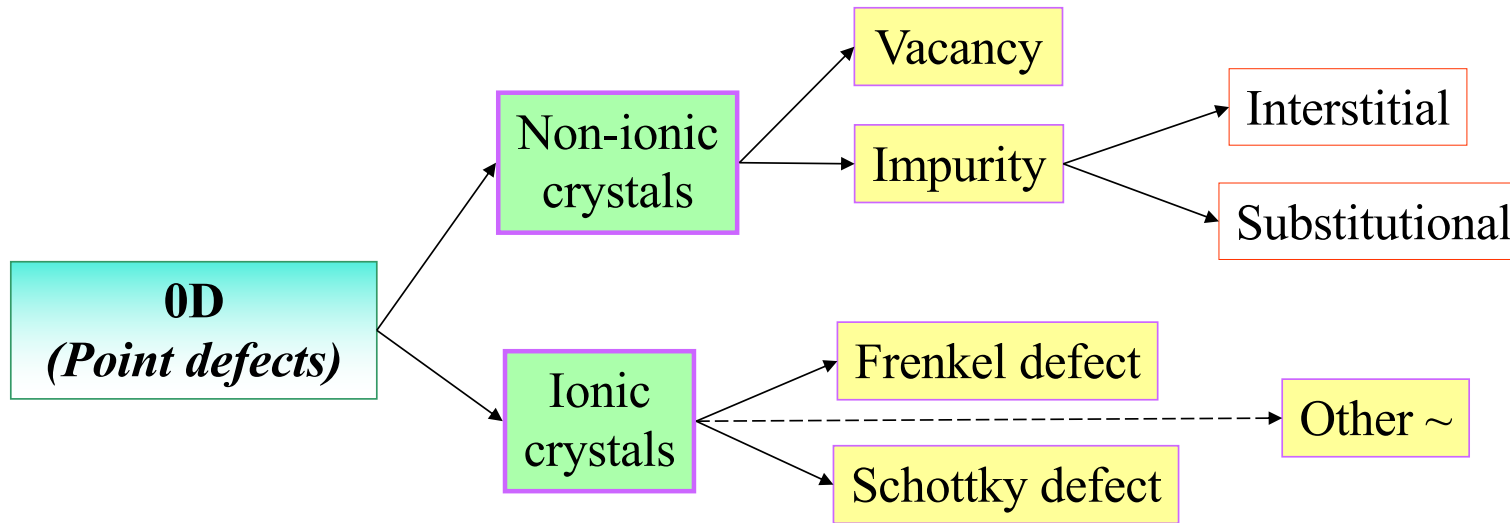
# Table of defect densities

Material	Impurity	Material	Impurity
Diamond	Nitrogen impurity 1%	Si wafers	$10^2 \text{ cm}^{-2}$
Blue Sapphire	0.01% Ti and Fe	SiC Wafers	$4 \times 10^3 - 5 \times 10^3 \text{ cm}^{-2}$
Ruby	1% Chromium	GaN wafers	$10^{10} \text{ cm}^{-2}$

An approximate defect density in steels?

# CLASSIFICATION OF DEFECTS BASED ON DIMENSIONALITY



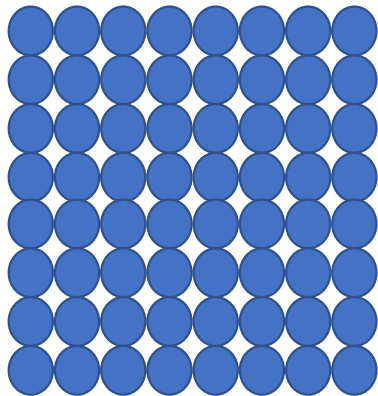


❑ Imperfect point-like regions in the crystal about the size of 1-2 atomic diameters

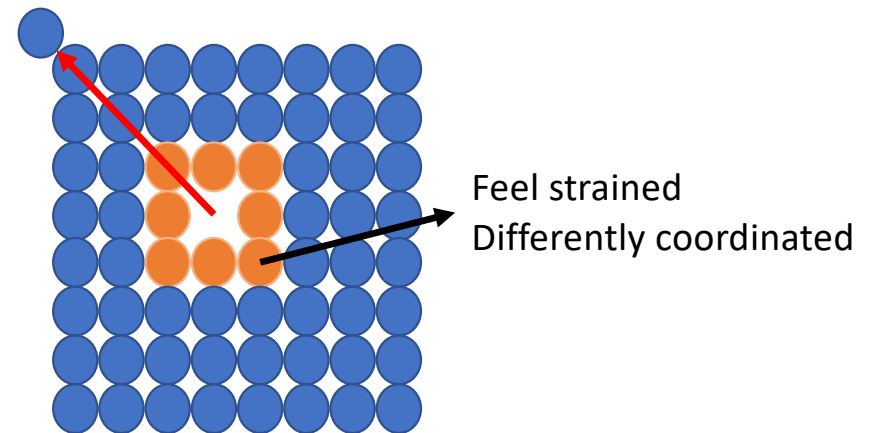
## Vacancy

- ❑ Missing atom from an atomic site
- ❑ Atoms around the vacancy displaced
- ❑ Tensile stress field produced in the vicinity

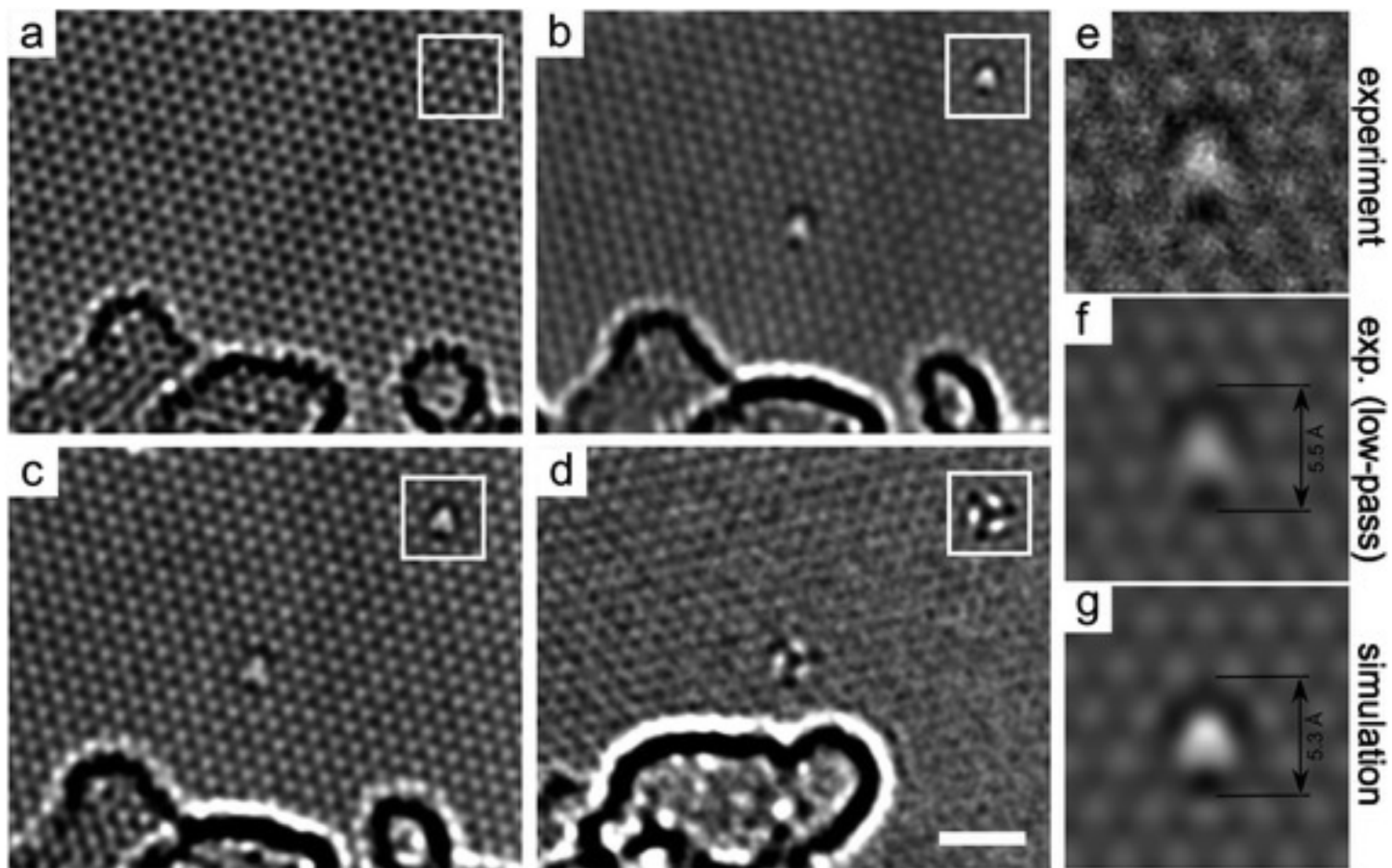
Perfect infinite 2D lattice



Displaced atom



Will the neighboring atoms face tensile or compressive strain ?

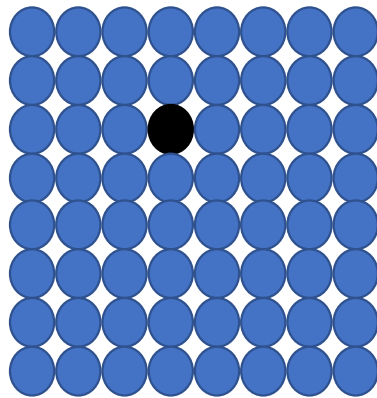


<https://pubs.rsc.org/en/content/articlehtml/2014/nr/c4nr01918k>

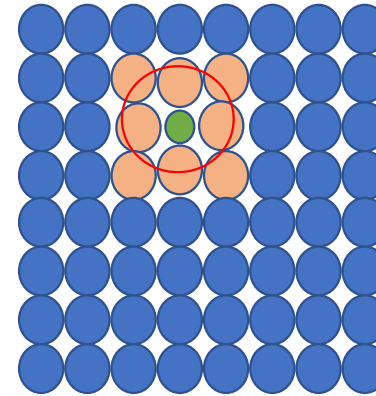


# Substitutional

Perfect infinite 2D lattice



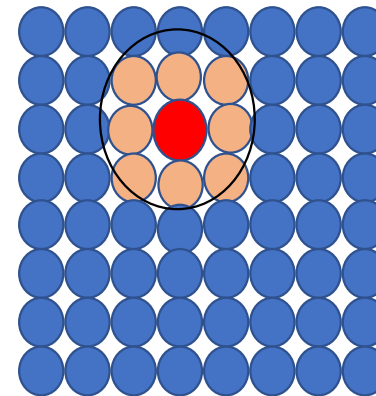
Substitution by a smaller atom



Boron doping in Si

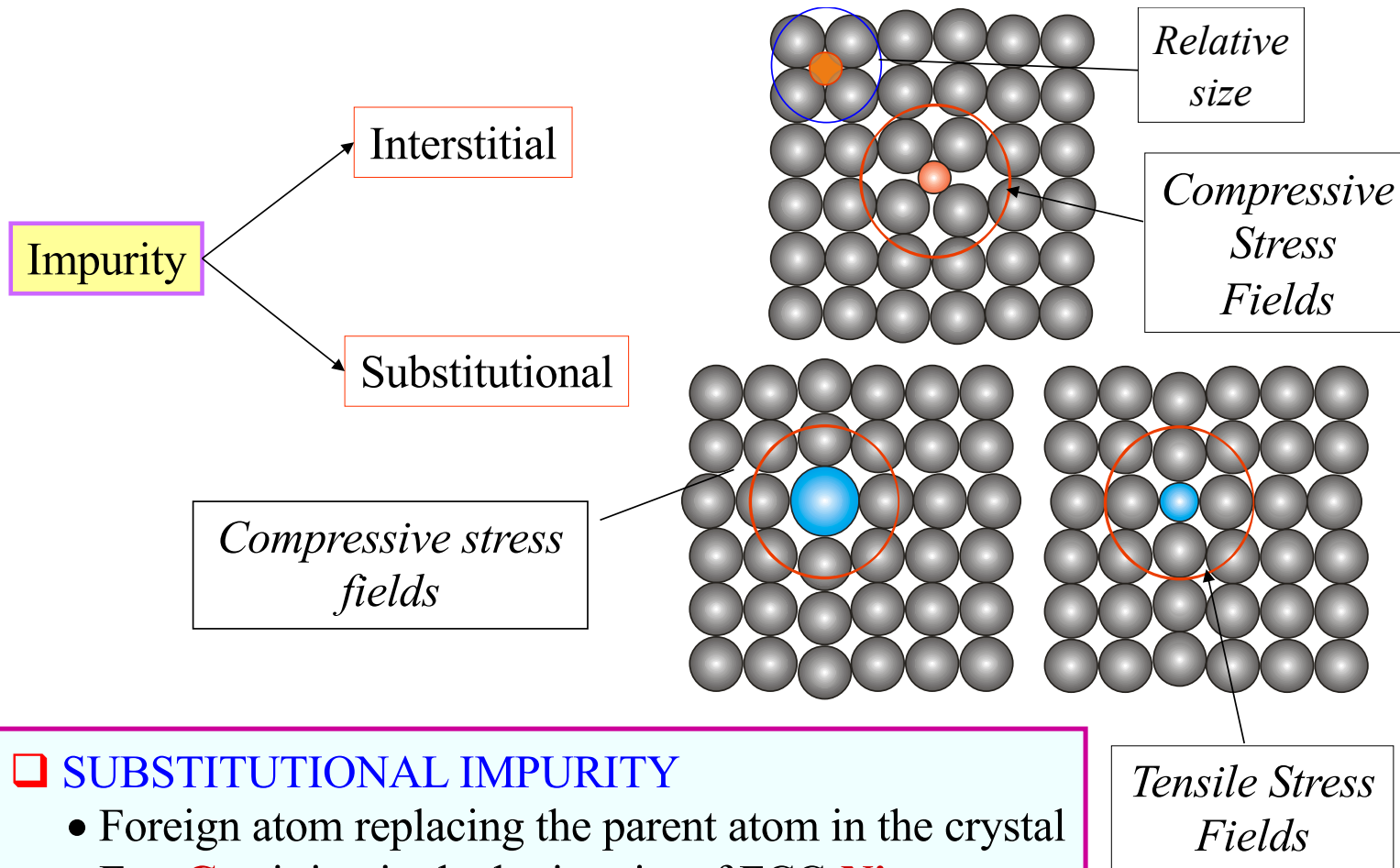
Being a smaller atom,  
The neighboring atoms  
are in tensile stress

Substitution by a larger atom



Arsenic doping in Si

Being a larger atom,  
The neighboring atoms  
are squeezed.  
There exists a  
compressive strain field



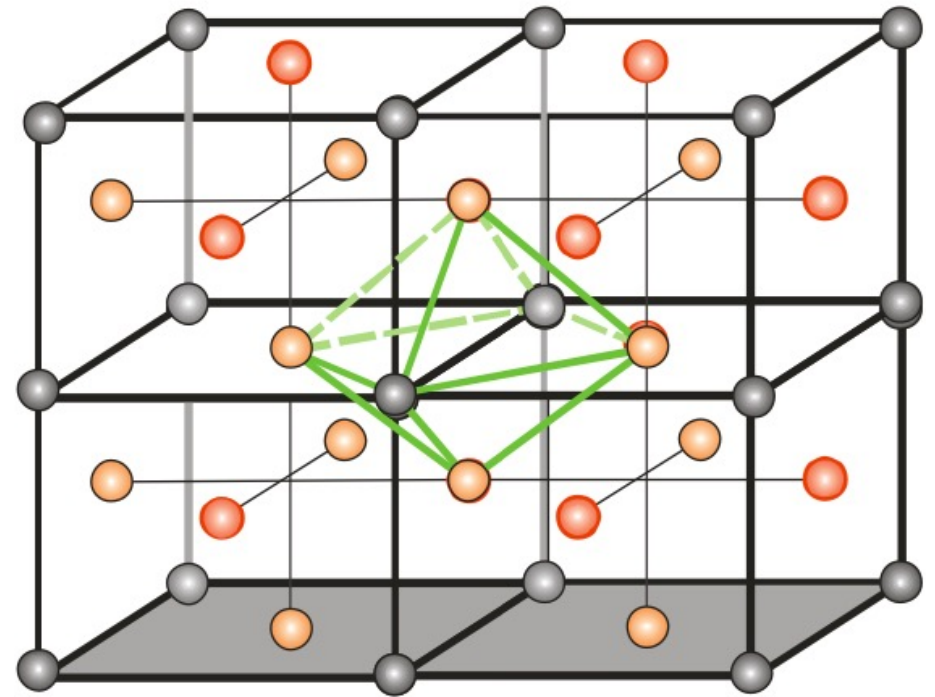
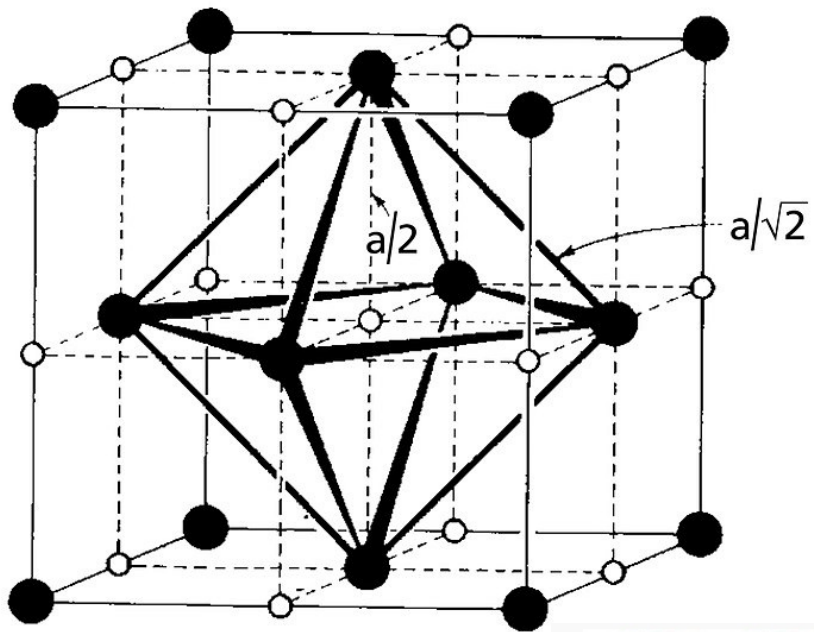
### ❑ SUBSTITUTIONAL IMPURITY

- Foreign atom replacing the parent atom in the crystal
- E.g. **Cu** sitting in the lattice site of FCC-**Ni**

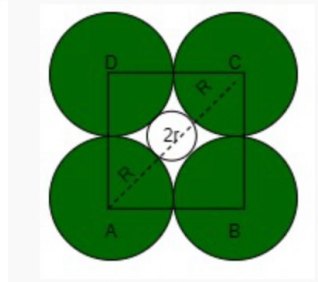
### ❑ INTERSTITIAL IMPURITY

- Foreign atom sitting in the void of a crystal
- E.g. **C** sitting in the octahedral void in HT FCC-**Fe**

# FCC Voids – Octahedral

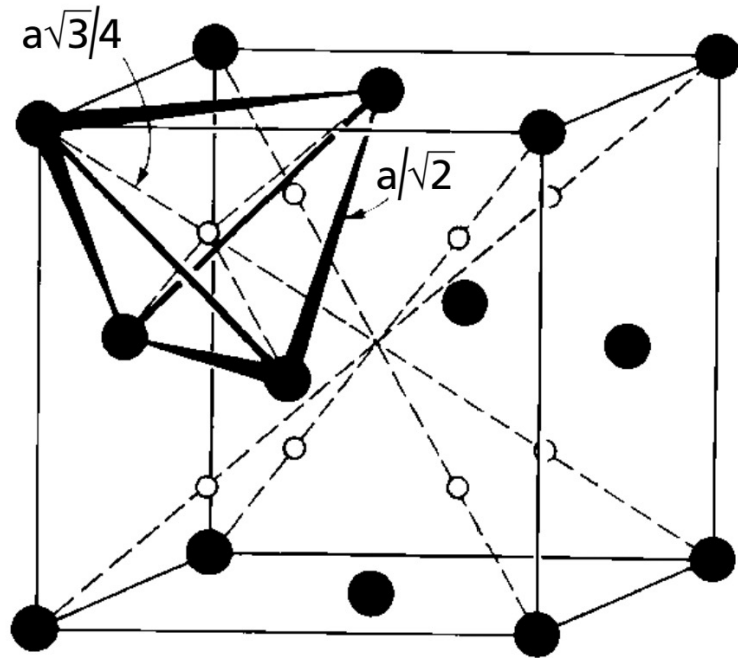


Size of atom that can be squeezed inside an octahedral void

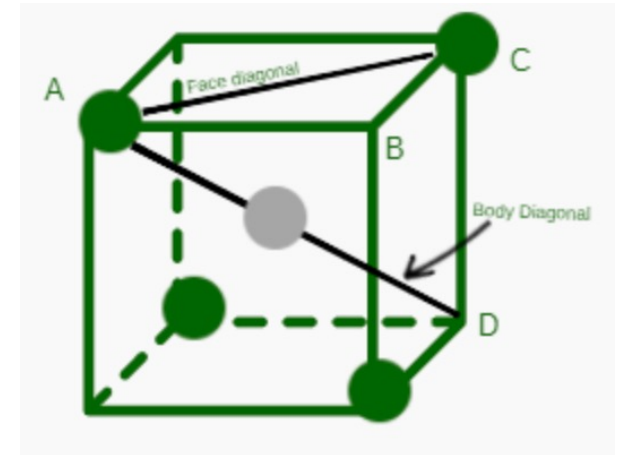
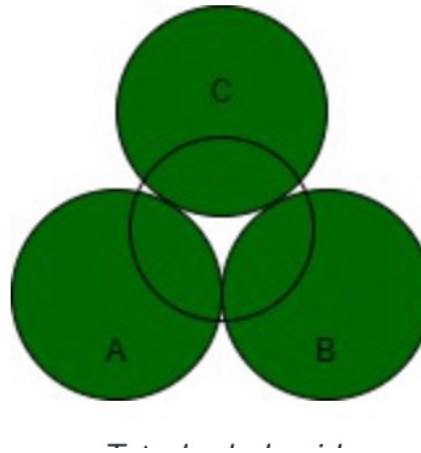


Octahedral void.  
 $r = 0.414R$

# FCC Voids - Tetrahedral



One void at each corner of the cube.



Geometric arguments leads to the size of atom squeezed into tetrahedral void

Tetrahedral void.

$$r = 0.225R$$

Interstitial **C** sitting in the octahedral void in HT FCC-**Fe**

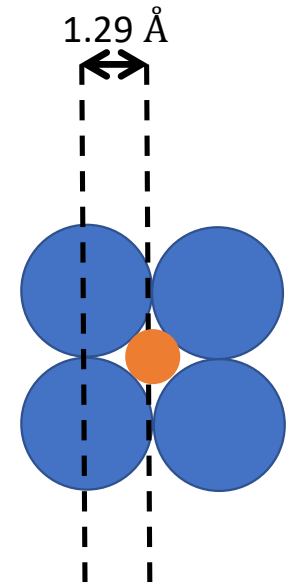
□  $r_{\text{Octahedral void}} / r_{\text{FCC atom}} = 0.414$

□  $r_{\text{Fe-FCC}} = 1.29 \text{ \AA} \Rightarrow r_{\text{Octahedral void}} = 0.414 \times 1.29 = 0.53 \text{ \AA}$

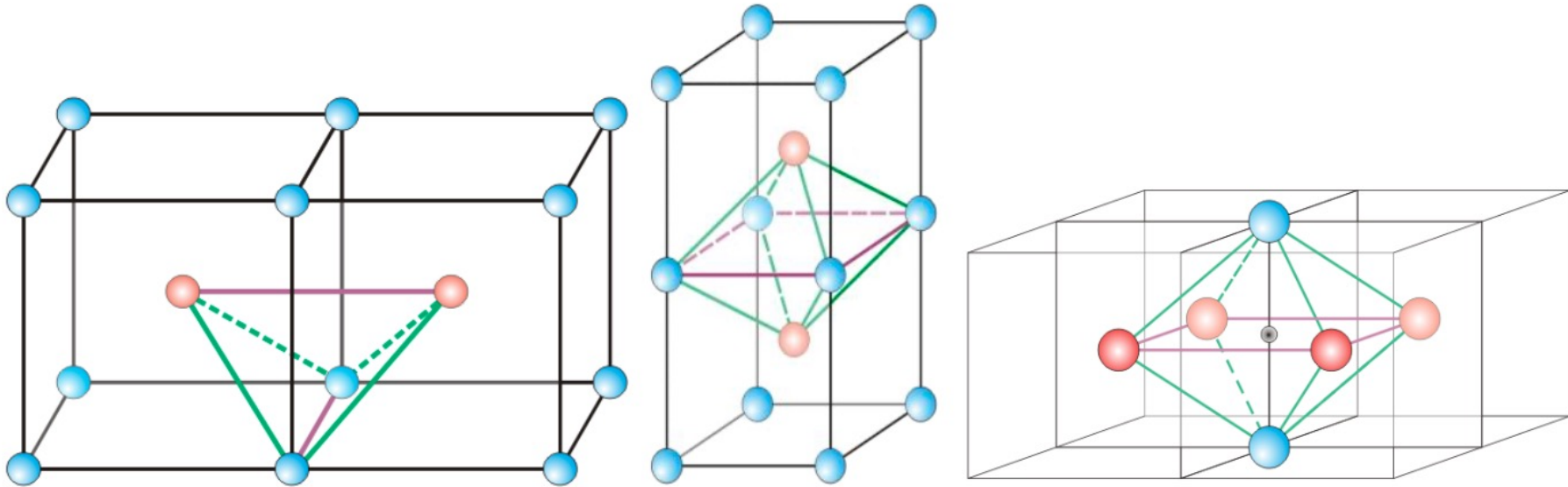
□  $r_{\text{C}} = 0.71 \text{ \AA}$

□  $\Rightarrow$  **Compressive strains** around the C atom

□ Solubility limited to **2 wt%** (9.3 at%)



What happens in BCC ? (Iron at low temperatures)

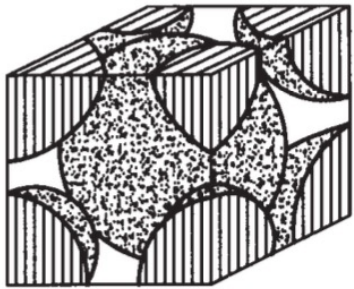


Two tetrahedral voids for each line of the cube – 12 TV

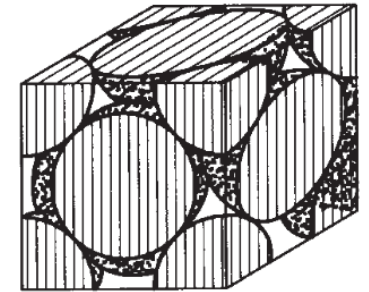
One octahedral void for each plane – 3 OV

For each line, there is another octahedral shared by four - 3

# Voids Comparison



	BCC	FCC
Tetrahedral void centers	Face $(1/2, 1/4, 0)$ and equivalent	Body diagonals $(1/4, 1/4, 1/4)$ and $(3/4, 3/4, 3/4)$
Number of tetrahedral voids	12	8
Tetrahedral void sizes	0.29 R	0.225R
Octahedral voids sizes	0.15 R	0.414R
Number of Octahedrons	6	4
Octahedron centers	Mid point of edges $(0, 0, 1/2)$ and equivalent	Body center $(1/2, 1/2, 1/2)$ and cell edges $(1/2, 0, 0)$ and equivalent



What does these information tell us about the carbon solubility in Iron at different temperatures ?

## Interstitial C sitting in the octahedral void in LT BCC-Fe

□  $r_{\text{Tetrahedral void}} / r_{\text{BCC atom}} = 0.29 \bullet r_{\text{C}} = 0.71 \text{ \AA}$

□  $r_{\text{Fe-BCC}} = 1.258 \text{ \AA} \Rightarrow r_{\text{Tetrahedral void}} = 0.29 \times 1.258 = 0.364 \text{ \AA}$

□ ► But C sits in smaller octahedral void- displaces fewer atoms

□  $\Rightarrow$  Severe compressive strains around the C atom

□ Solubility limited to 0.008 wt% (0.037 at%)

- Remember, voids in BCC are all distorted.
- Octahedral is asymmetric with two atoms very close